

TK40P04M1

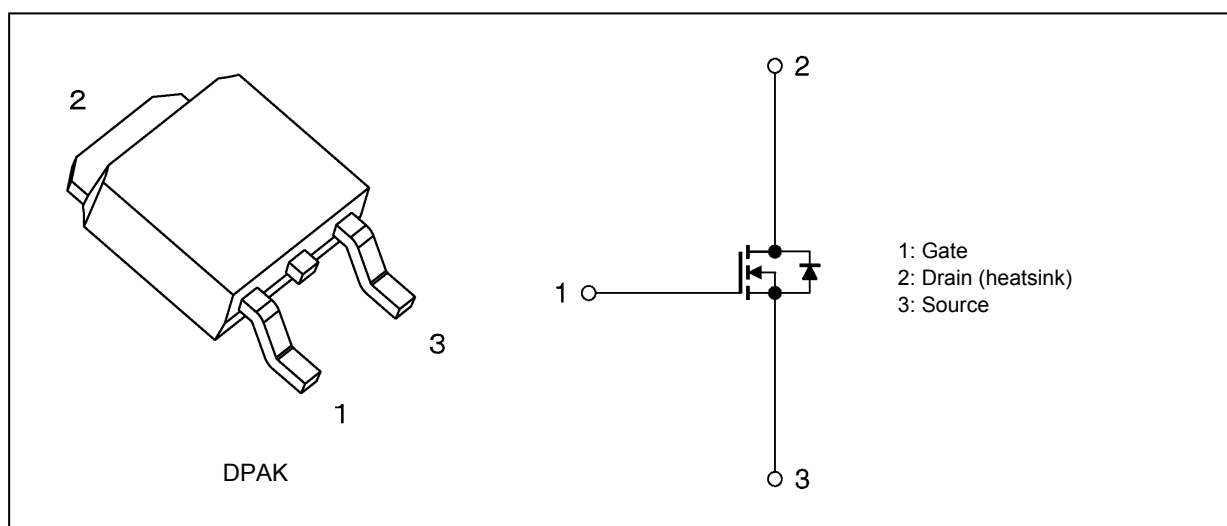
1. Applications

- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Low gate charge: $Q_{SW} = 7.4 \text{ nC (typ.)}$
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 8.5 \text{ m}\Omega \text{ (typ.) (} V_{GS} = 10 \text{ V)}$
- (4) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A (max) (} V_{DS} = 40 \text{ V)}$
- (5) Enhancement mode: $V_{th} = 1.3 \text{ to } 2.3 \text{ V (} V_{DS} = 10 \text{ V, } I_D = 0.2 \text{ mA)}$

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	40	V
Gate-source voltage	V_{GSS}	± 20	
Drain current (DC)	I_D	40	A
Drain current (pulsed)	I_{DP}	120	
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	47	W
Single-pulse avalanche energy	E_{AS}	41	mJ
Avalanche current	I_{AR}	40	A
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	2.65	°C/W
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 32\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 20\ \mu\text{H}$, $R_G = 25\ \Omega$, $I_{AR} = 40\text{ A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 40\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	40	—	—	V
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	25	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}, I_D = 0.2\text{ mA}$	1.3	—	2.3	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 4.5\text{ V}, I_D = 20\text{ A}$	—	10.3	13.4	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}, I_D = 20\text{ A}$	—	8.5	11	

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1920	—	pF
Reverse transfer capacitance	C_{rss}		—	90	—	
Output capacitance	C_{oss}		—	310	—	
Gate resistance	r_g	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 5\text{ MHz}$	—	1.6	3.5	Ω
Switching time (rise time)	t_r	See Figure 6.2.1.	—	20	—	ns
Switching time (turn-on time)	t_{on}		—	27	—	
Switching time (fall time)	t_f		—	18	—	
Switching time (turn-off time)	t_{off}		—	63	—	

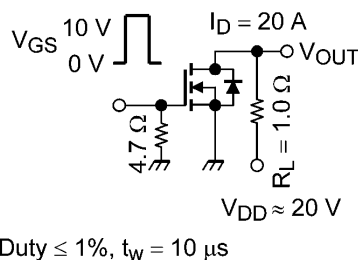


Fig. 6.2.1 Switching Time Test Circuit

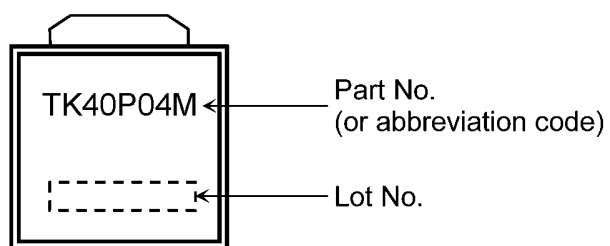
6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 32\text{ V}, V_{GS} = 10\text{ V}, I_D = 40\text{ A}$	—	29	—	nC
		$V_{DD} \approx 32\text{ V}, V_{GS} = 5\text{ V}, I_D = 40\text{ A}$	—	15	—	
Gate-source charge 1	Q_{gs1}	$V_{DD} \approx 32\text{ V}, V_{GS} = 10\text{ V}, I_D = 40\text{ A}$	—	6.0	—	
Gate-drain charge	Q_{gd}		—	4.7	—	
Gate switch charge	Q_{sw}		—	7.4	—	

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed)	(Note 3) I_{DRP}	—	—	—	120	A
Diode forward voltage	V_{DSF}	$I_{DR} = 40\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V

Note 3: Ensure that the channel temperature does not exceed 150°C .

7. Marking**Fig. 7.1 Marking**

8. Characteristics Curves (Note)

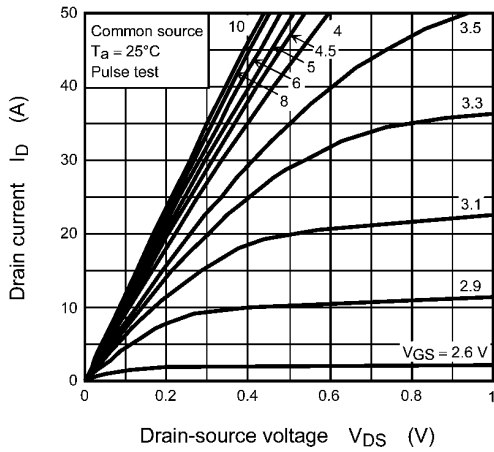


Fig. 8.1 $I_D - V_{DS}$

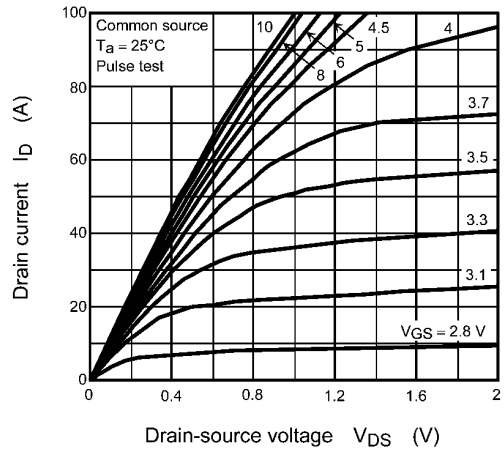


Fig. 8.2 $I_D - V_{DS}$

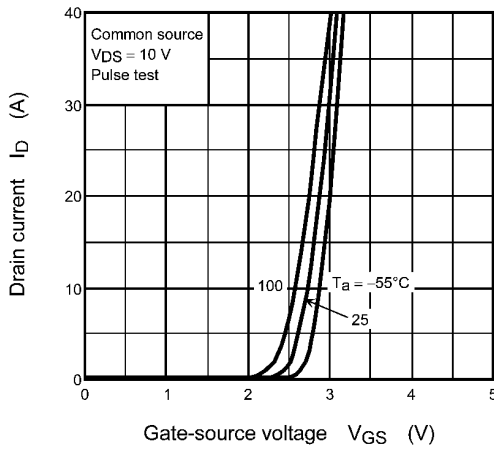


Fig. 8.3 $I_D - V_{GS}$

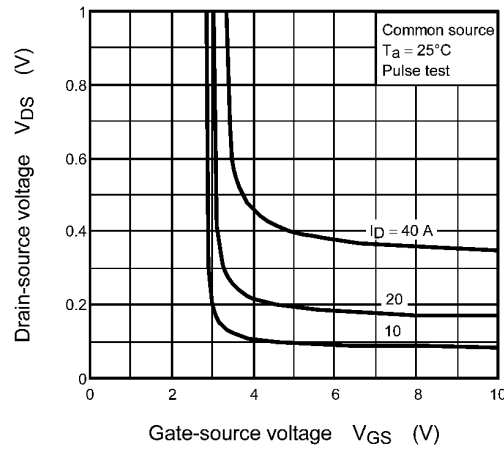


Fig. 8.4 $V_{DS} - V_{GS}$

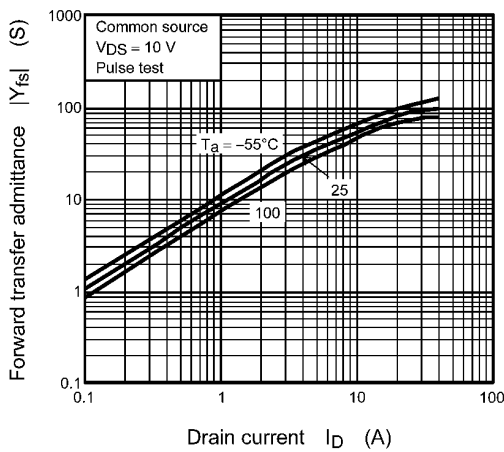


Fig. 8.5 $|Y_{fs}| - I_D$

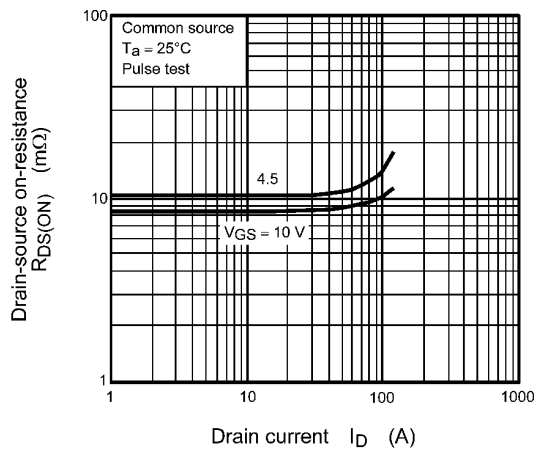


Fig. 8.6 $R_{DS(ON)} - I_D$

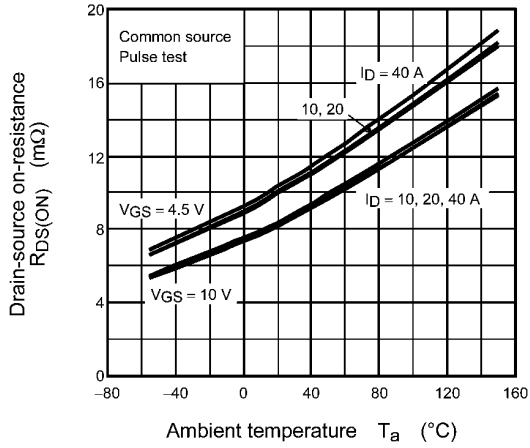


Fig. 8.7 $R_{DS(ON)} - T_a$

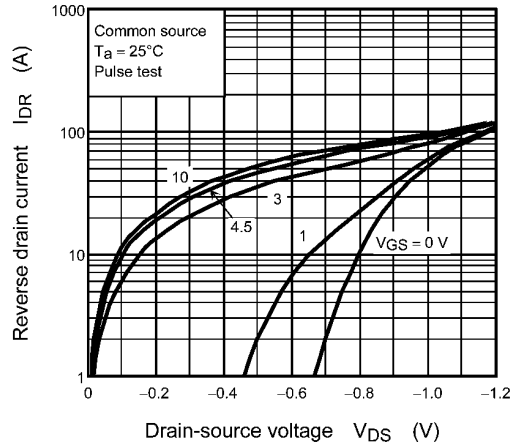


Fig. 8.8 $I_{DR} - V_{DS}$

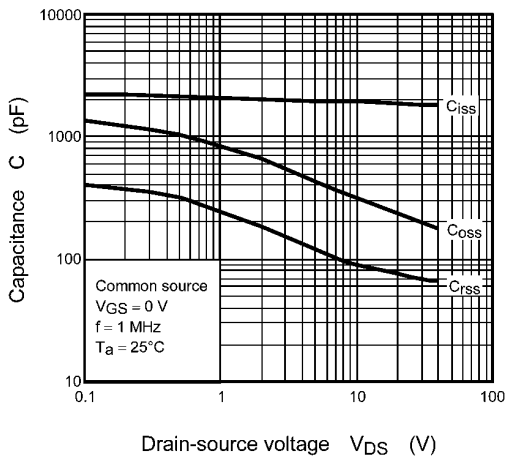


Fig. 8.9 Capacitance - V_{DS}

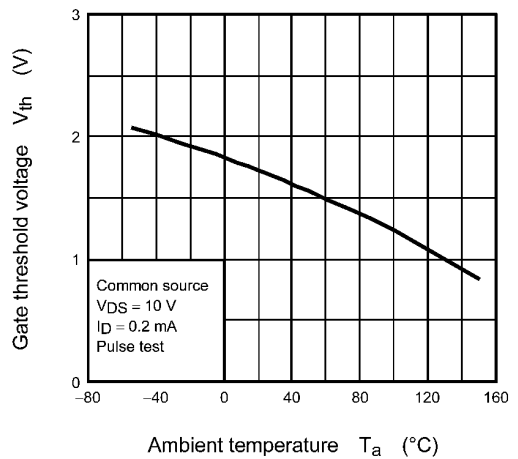


Fig. 8.10 $V_{th} - T_a$

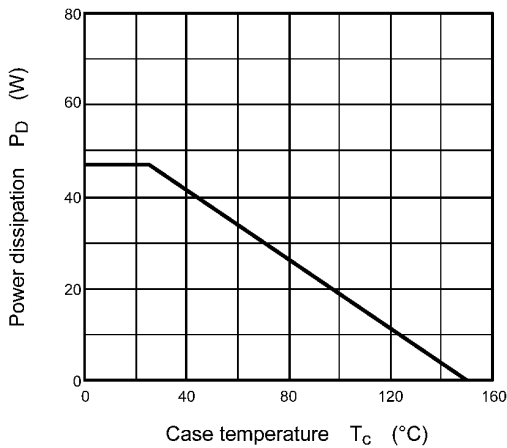


Fig. 8.11 $P_D - T_c$
(Guaranteed Maximum)

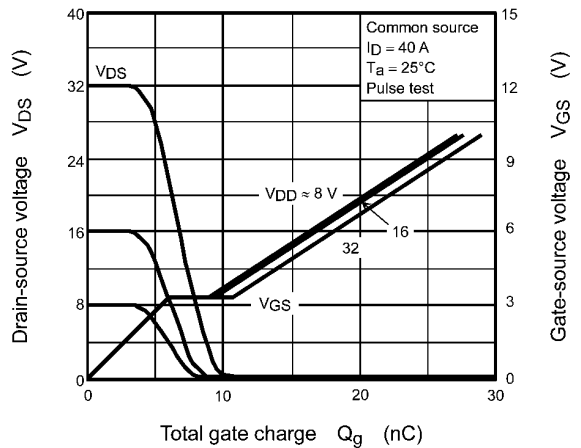


Fig. 8.12 Dynamic Input/Output Characteristics

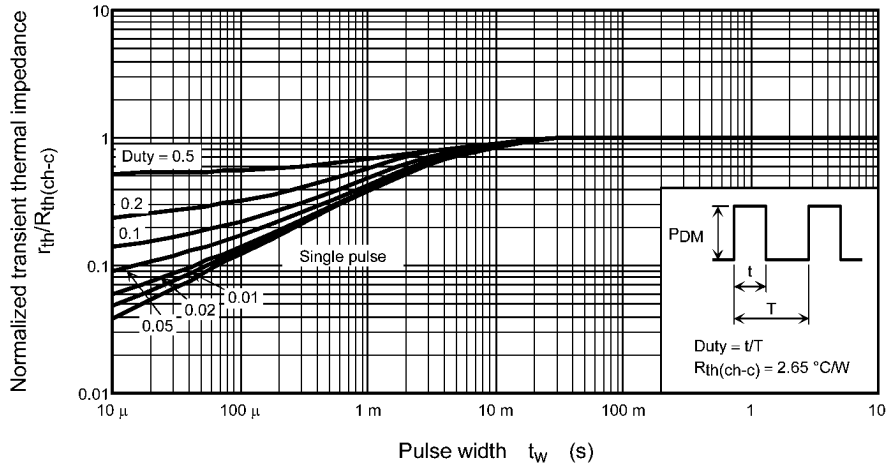


Fig. 8.13 $r_{th}/R_{th(ch-c)} - t_w$
(Guaranteed Maximum)

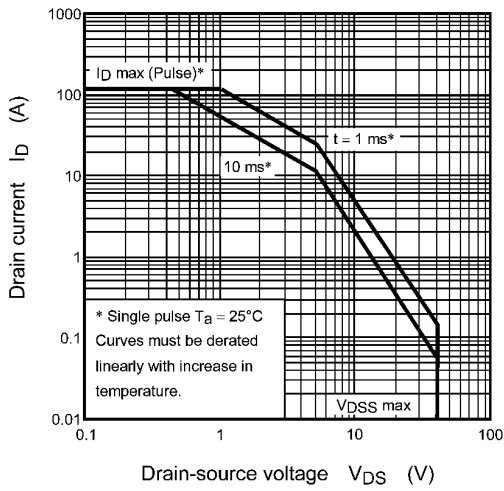


Fig. 8.14 Safe Operating Area
(Guaranteed Maximum)

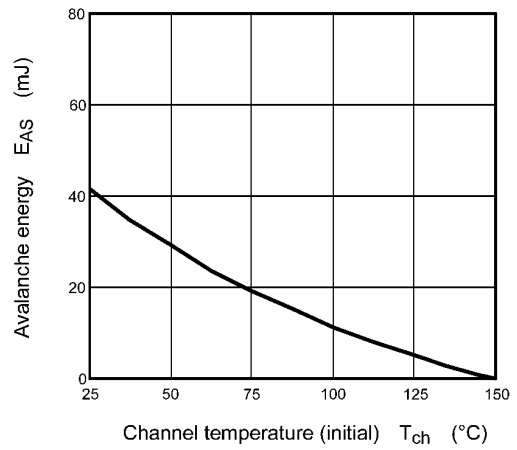


Fig. 8.15 $E_{AS} - T_{ch}$
(Guaranteed Maximum)

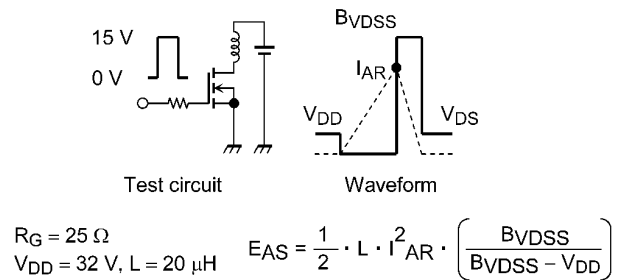
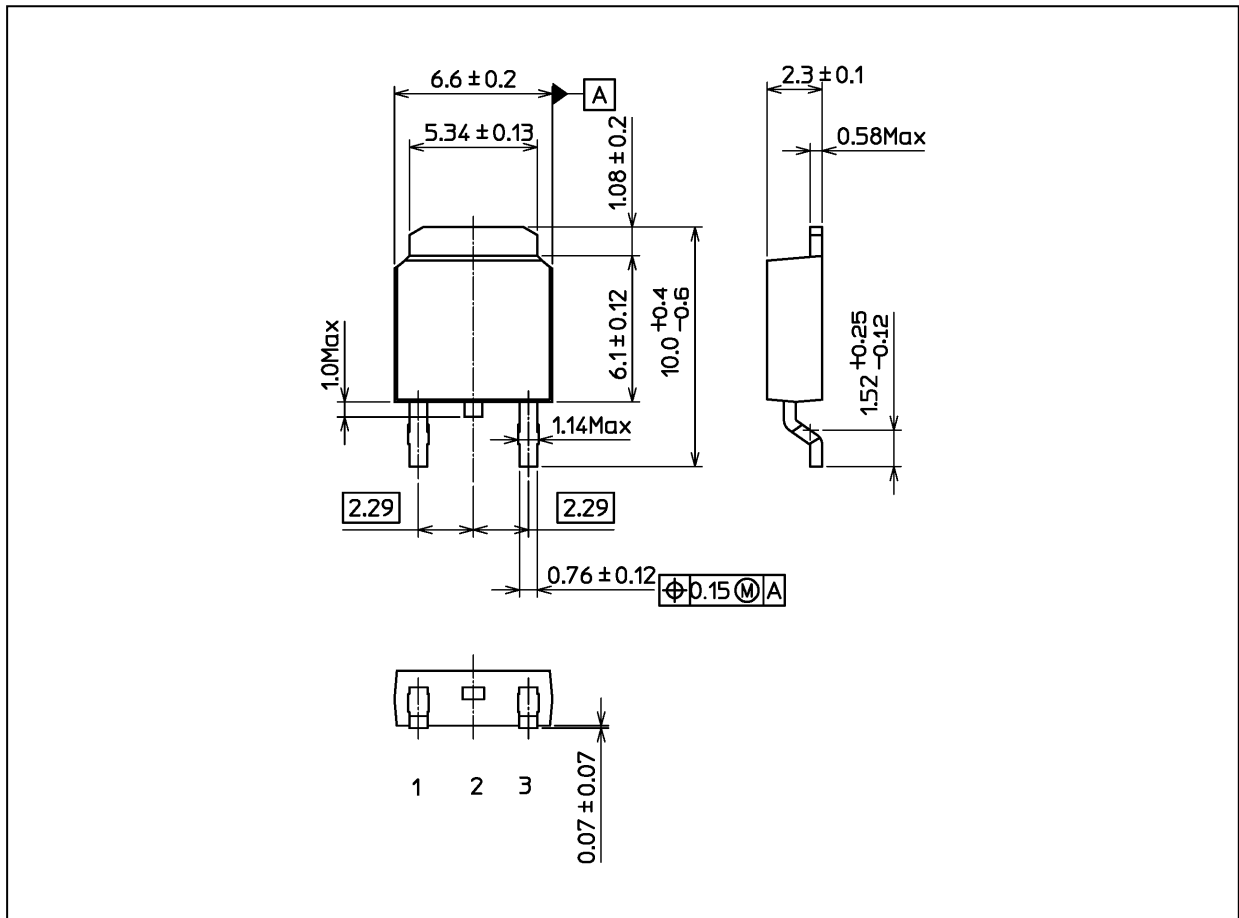


Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

Package Name(s)
TOSHIBA: 2-7K1S
Nickname: DPAK

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